



US007508476B2

(12) **United States Patent**
Huang

(10) **Patent No.:** **US 7,508,476 B2**
(45) **Date of Patent:** **Mar. 24, 2009**

(54) **MULTI-DOMAIN VERTICAL ALIGNMENT LCD PANEL WITH PLURALITY OF MAIN SLITS CORRESPONDING TO EDGE OF DIELECTRIC LINING LAYERS IN PIXEL ELECTRODE OF THIN FILM TRANSISTOR ARRAY**

2003/0133055 A1 7/2003 Um et al. 349/43
2004/0070715 A1 4/2004 Ma et al. 349/130
2005/0140870 A1 6/2005 Kim et al. 349/114

FOREIGN PATENT DOCUMENTS

CN	1270326	10/2000
CN	1606125	4/2005
CN	1661448	8/2005
JP	2000-17194	6/2000
JP	2003-043489	2/2003
JP	2004-301878	10/2004
JP	2004-302267	10/2004

(75) Inventor: **Chun-Yi Huang**, Dayuan Township, Taoyuan County (TW)

(73) Assignee: **Chunghwa Picture Tubes, Ltd.**, Taiepi (TW)

(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 433 days.

(21) Appl. No.: **11/259,425**

(22) Filed: **Oct. 25, 2005**

(65) **Prior Publication Data**

US 2007/0046878 A1 Mar. 1, 2007

(30) **Foreign Application Priority Data**

Aug. 25, 2005 (TW) 94129055 A

(51) **Int. Cl.**
G02F 1/1337 (2006.01)

(52) **U.S. Cl.** **349/130**; 349/129

(58) **Field of Classification Search** 349/129,
349/130

See application file for complete search history.

(56) **References Cited**

U.S. PATENT DOCUMENTS

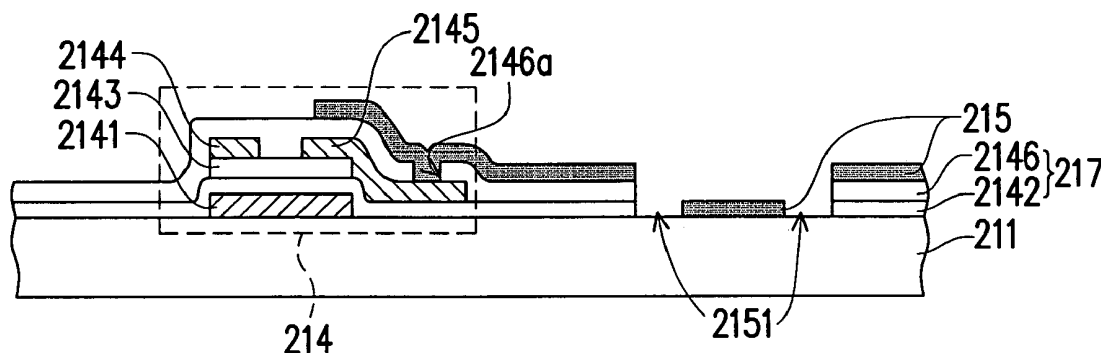
2002/0030781 A1 3/2002 Kim et al. 349/143

Primary Examiner—David Nelms
Assistant Examiner—John Heyman
(74) *Attorney, Agent, or Firm*—J.C. Patents

(57) **ABSTRACT**

A multi-domain vertical alignment liquid crystal display panel, a thin film transistor array, and methods of fabrication the same are provided. The TFT array substrate comprises a substrate, data lines, scan lines and pixel structures. The data lines and the scan lines are arranged on the substrate to define a plurality of pixel regions. Each pixel structure is arranged in the corresponding pixel region. Each pixel structure comprises a TFT, a pixel electrode and a dielectric lining layer. The TFT is electrically connected to the corresponding data line and the corresponding scan line. The pixel electrode having slits is placed upon the TFT and is electrically connected thereto. The dielectric lining layer is disposed on the substrate. Part of the dielectric lining layer is sandwiched between the pixel electrode and the substrate, to make the liquid crystal molecules inside the liquid crystal display have more tilt directions.

13 Claims, 9 Drawing Sheets



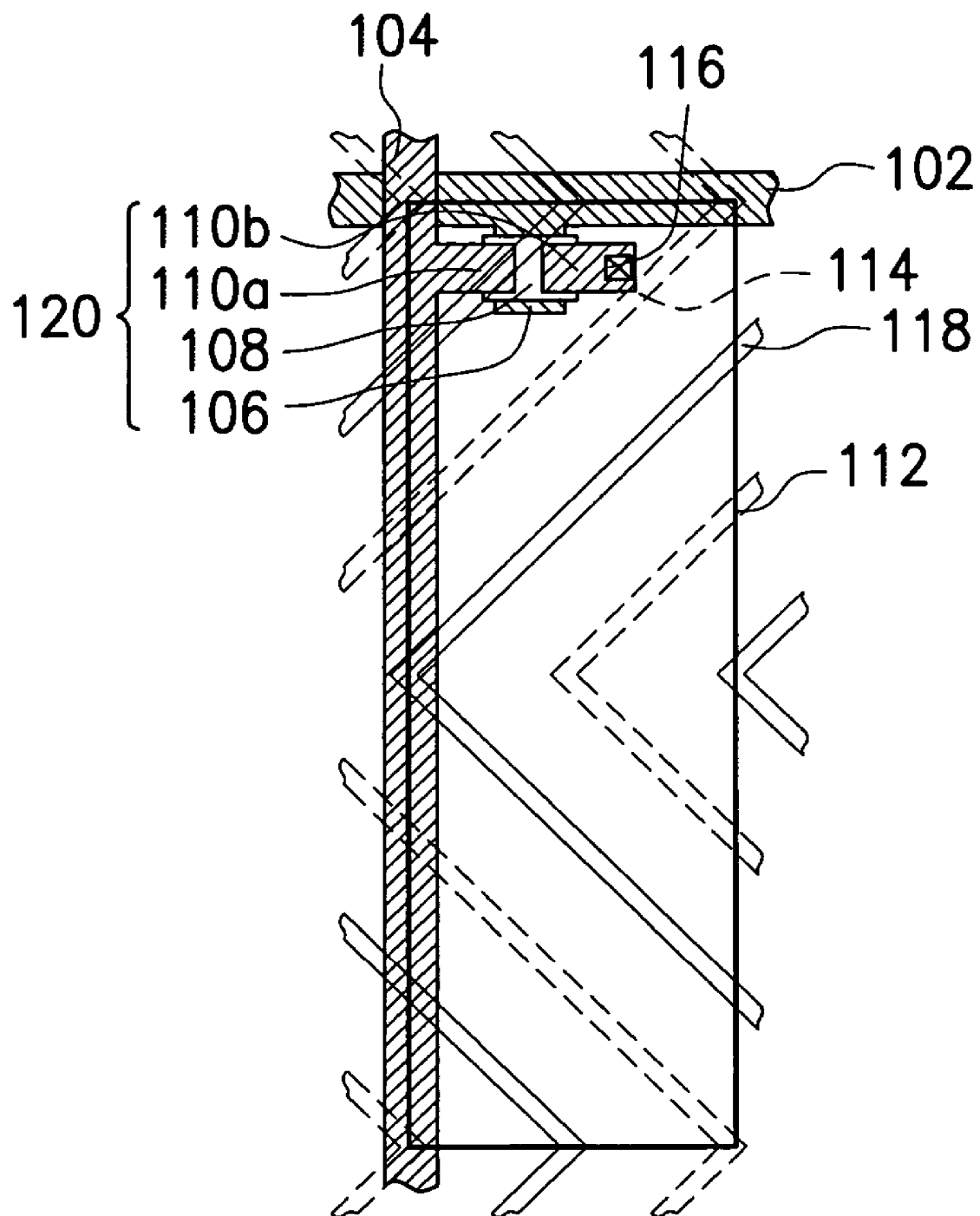
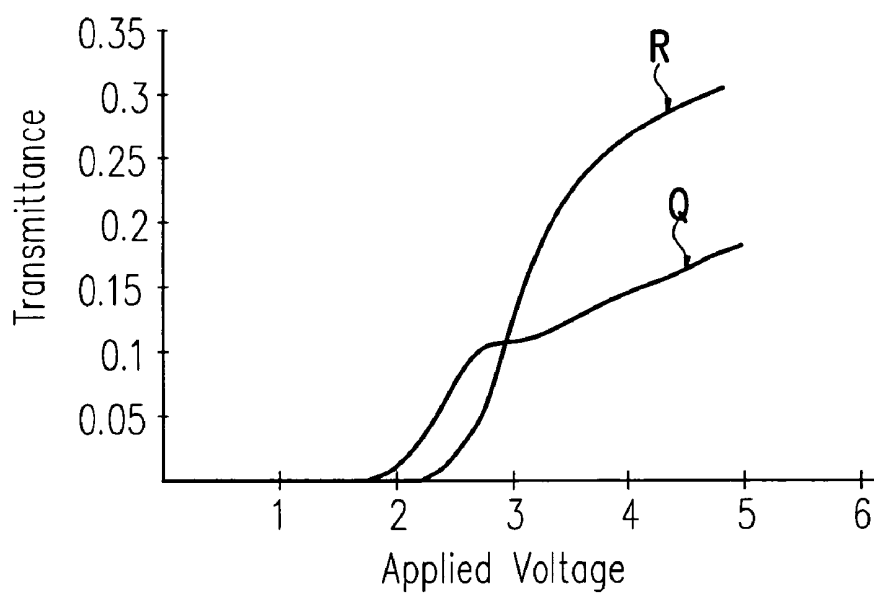
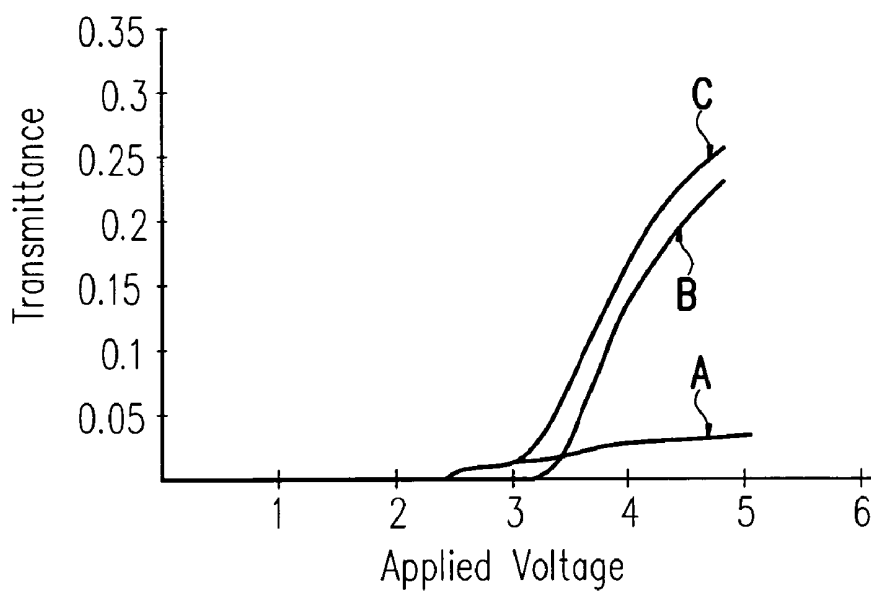


FIG. 1 (PRIOR ART)

**FIG. 2 (PRIOR ART)****FIG. 3**

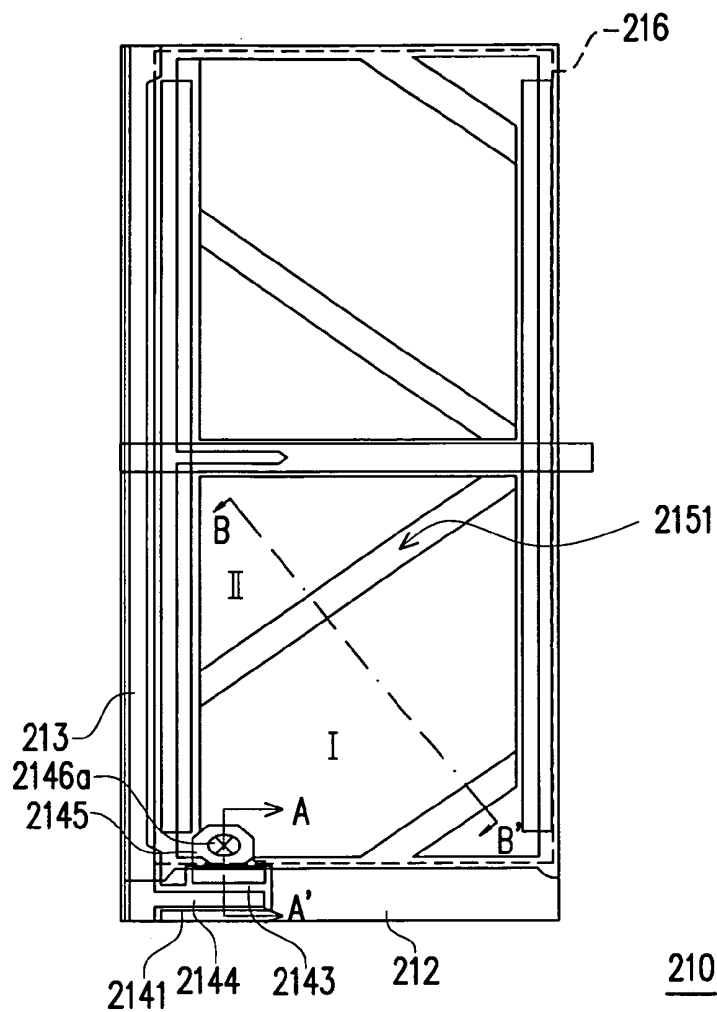


FIG. 4A

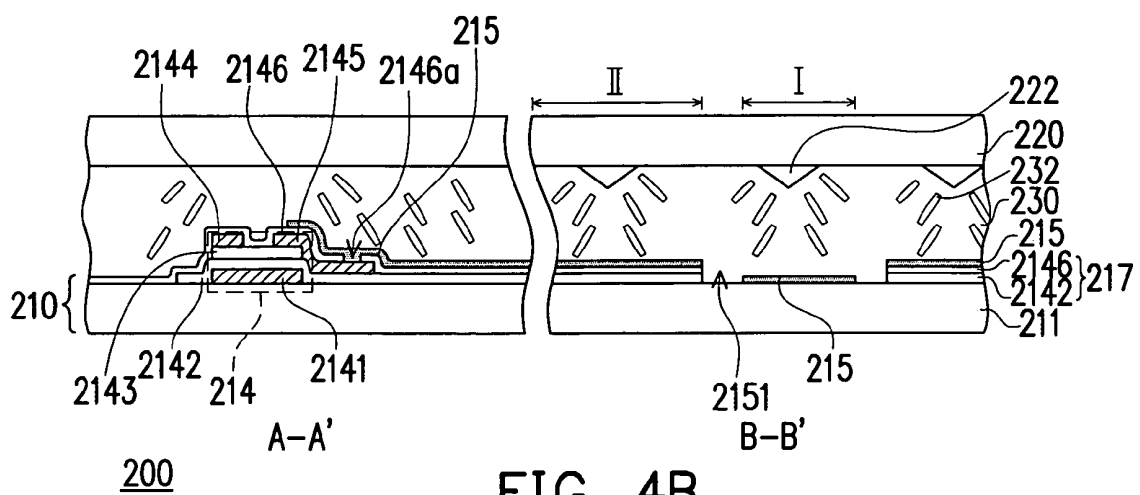


FIG. 4B

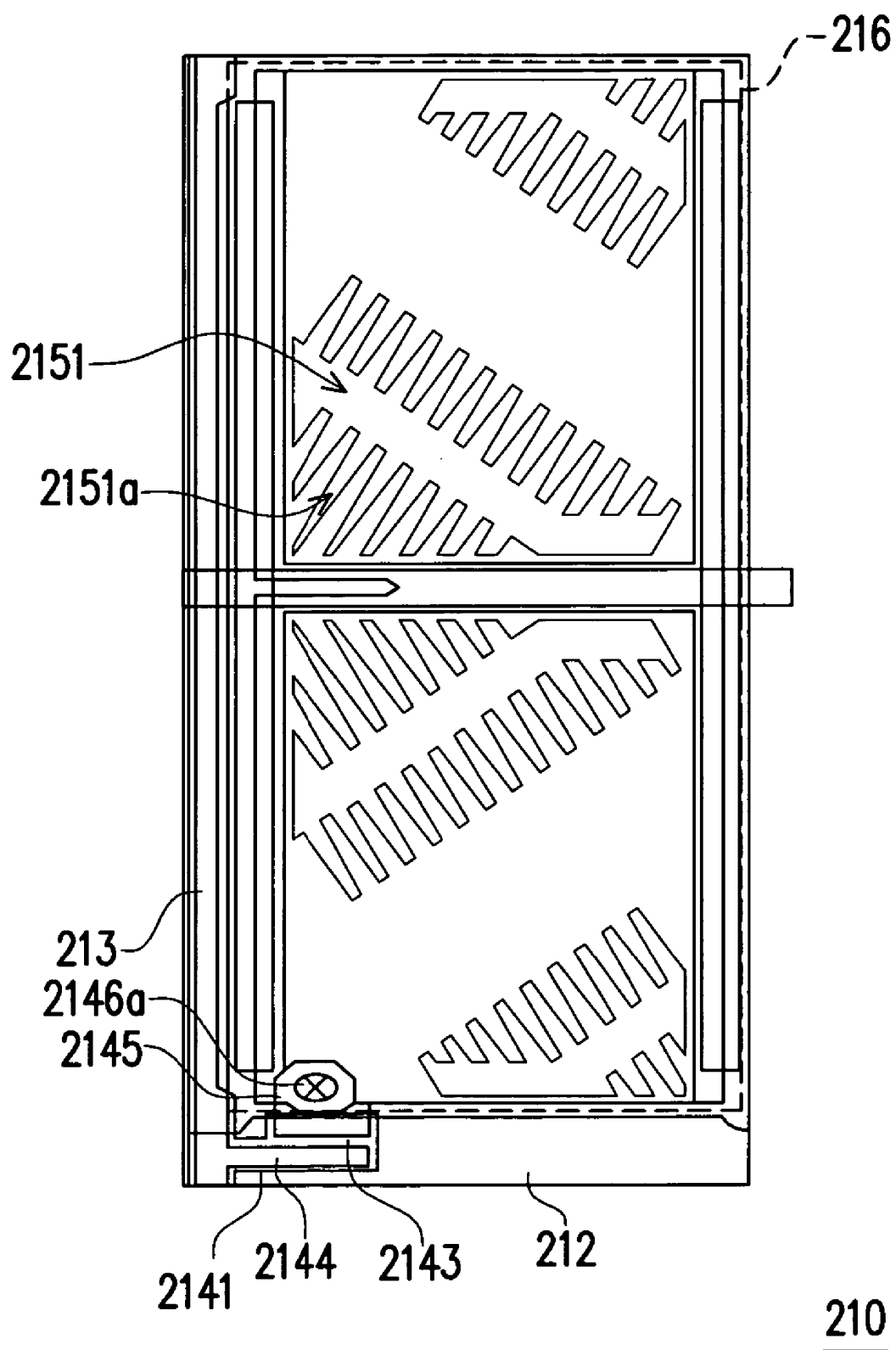


FIG. 5

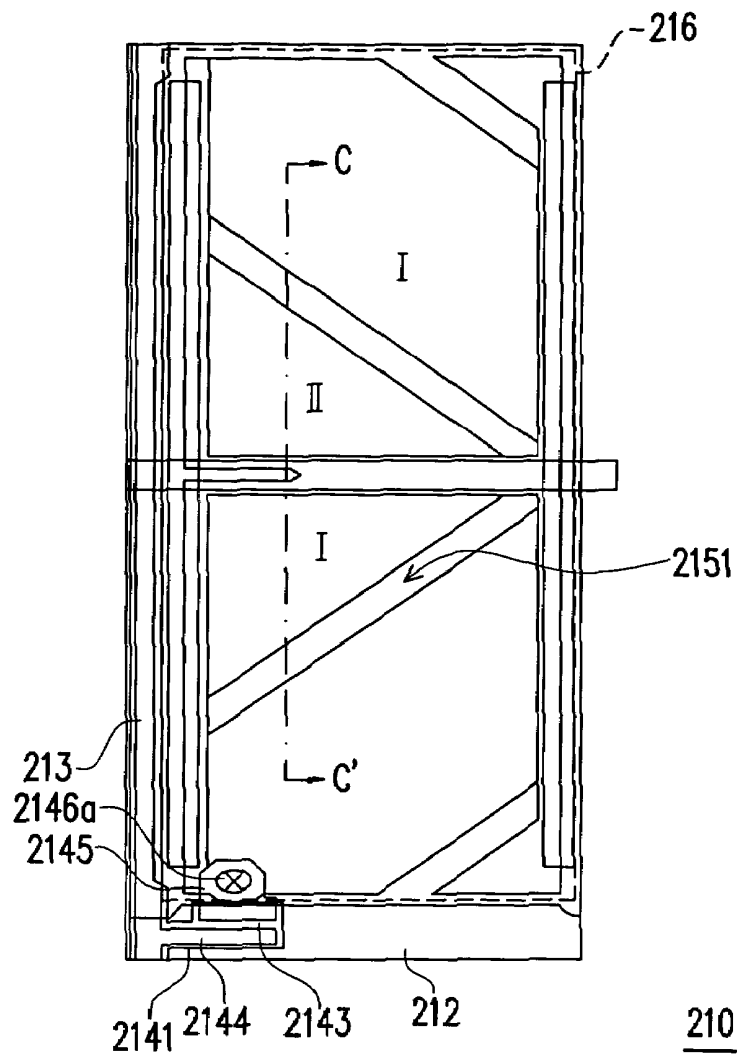


FIG. 6A

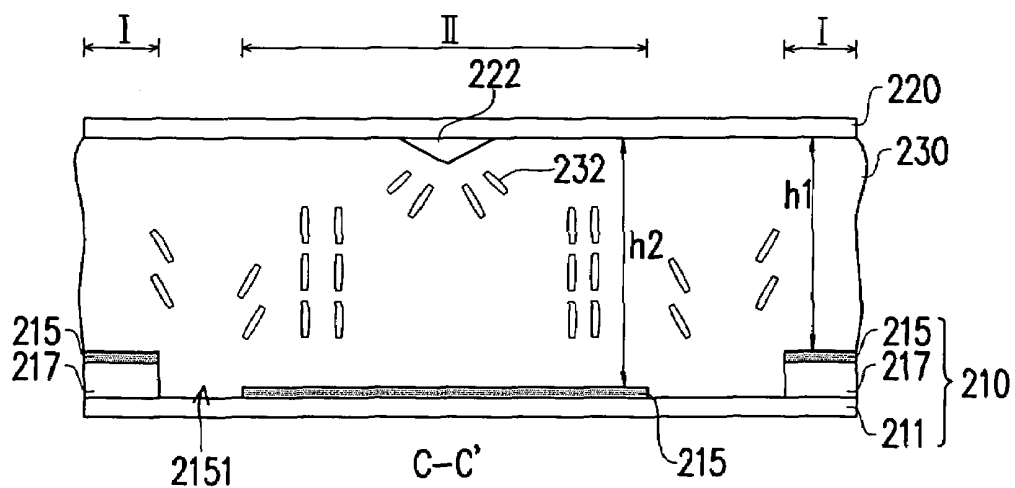


FIG. 6B

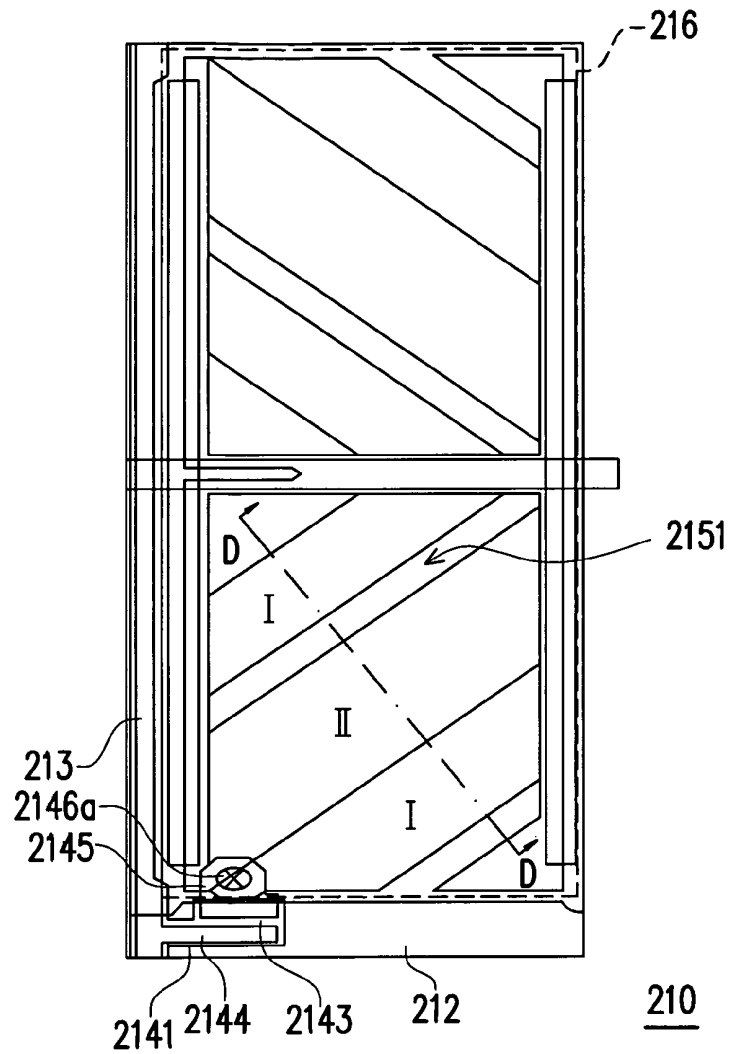


FIG. 7A

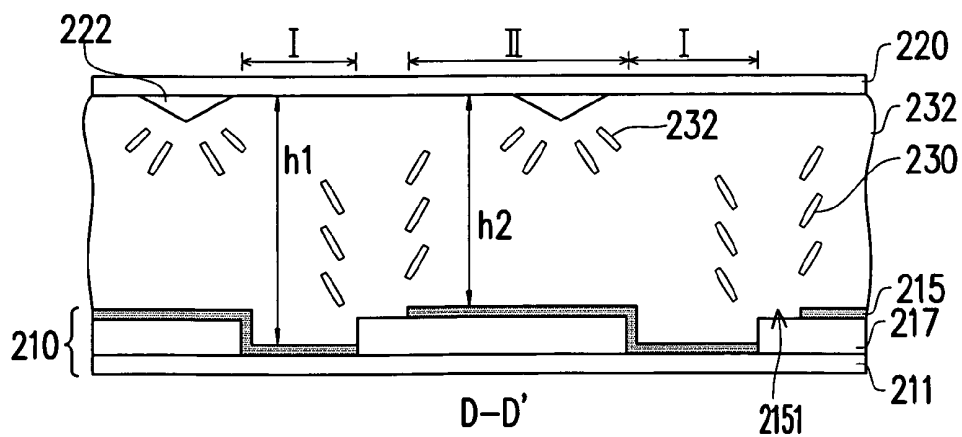


FIG. 7B

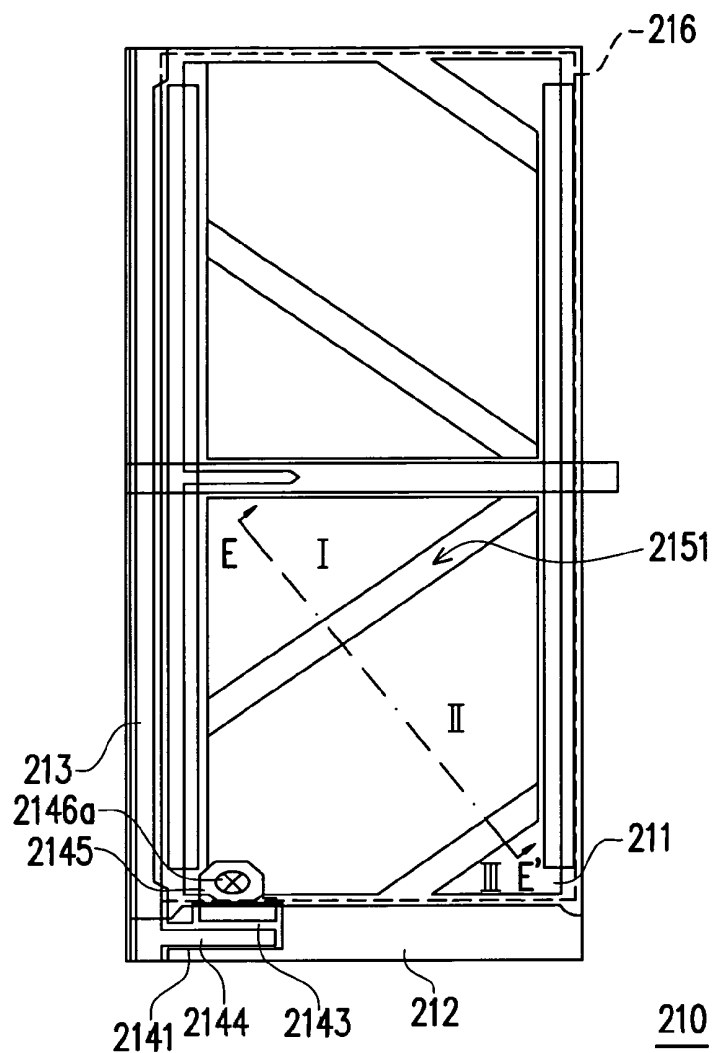


FIG. 8A

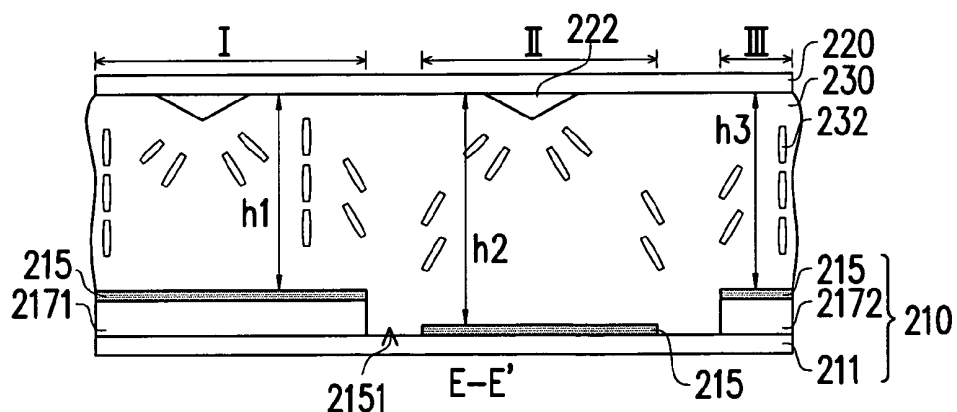


FIG. 8B



FIG. 9A

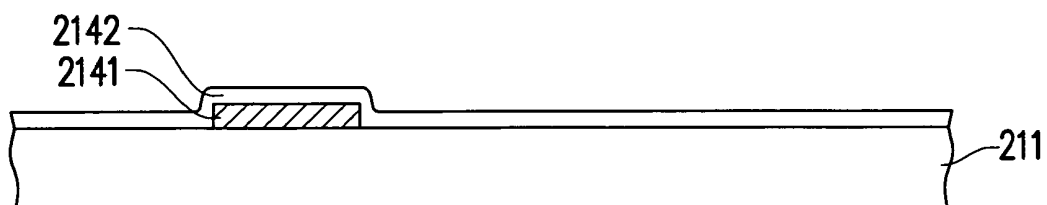


FIG. 9B

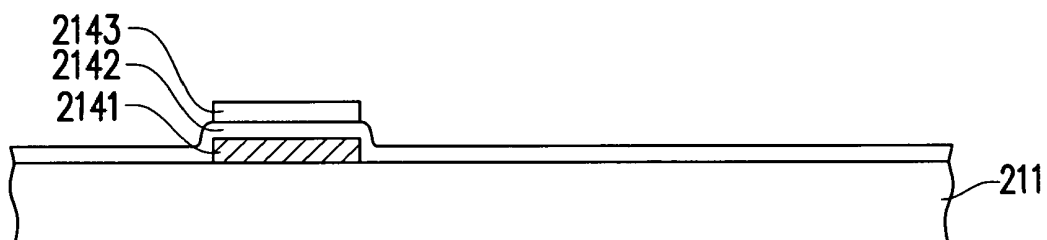


FIG. 9C

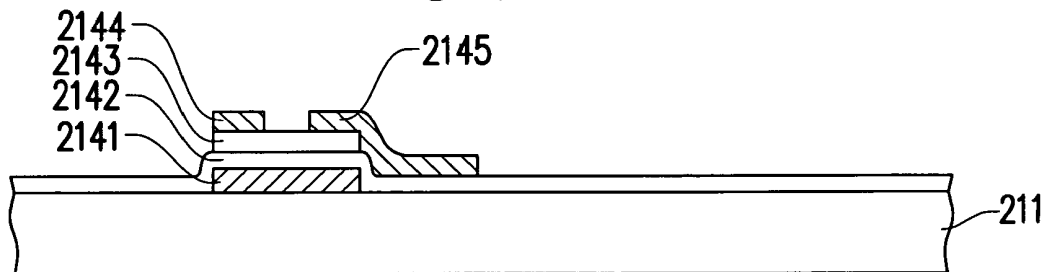


FIG. 9D

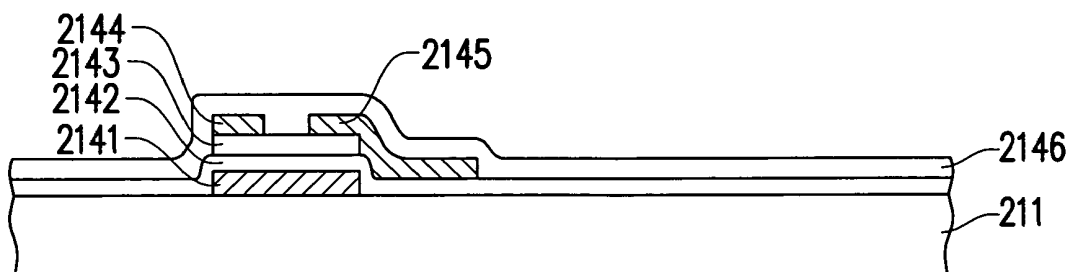
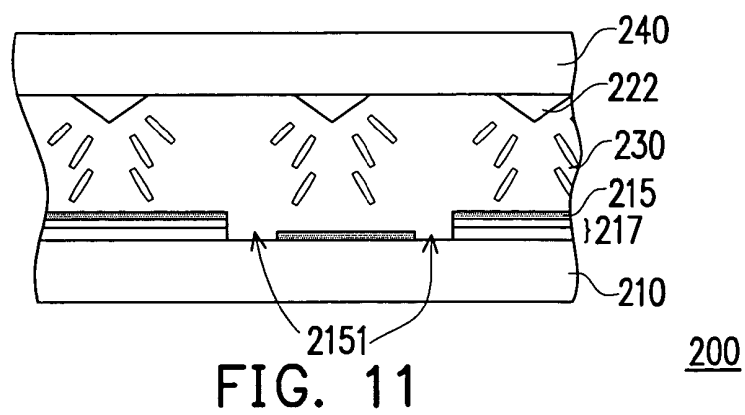
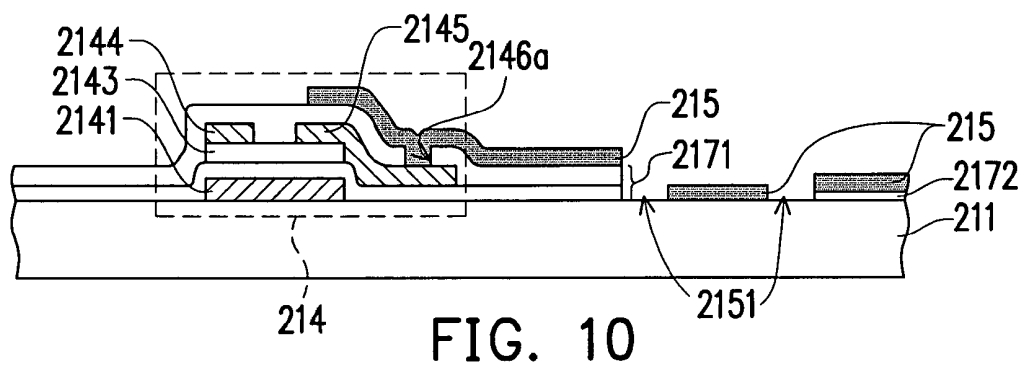
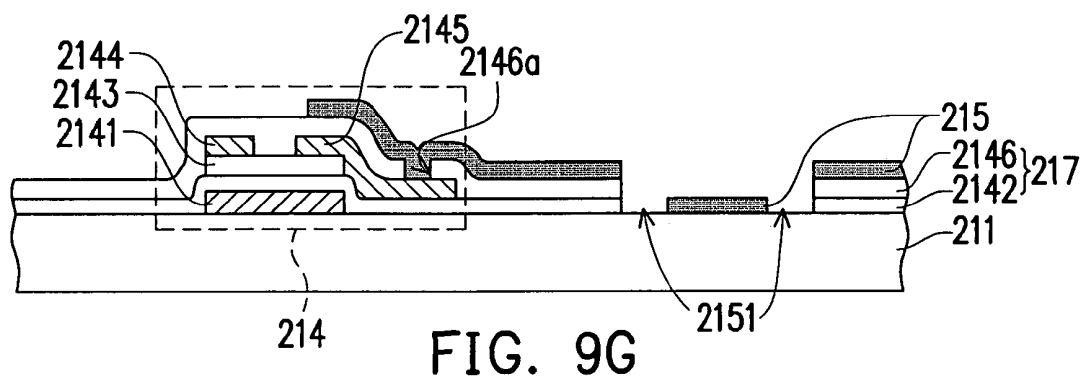
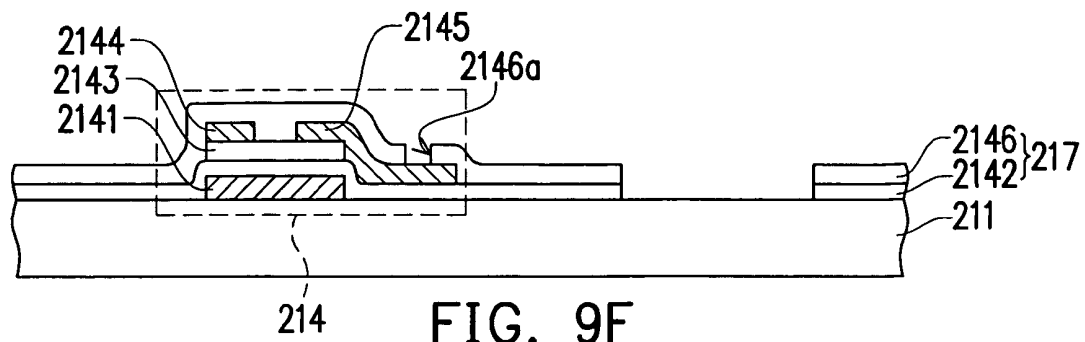


FIG. 9E



MULTI-DOMAIN VERTICAL ALIGNMENT LCD PANEL WITH PLURALITY OF MAIN SLITS CORRESPONDING TO EDGE OF DIELECTRIC LINING LAYERS IN PIXEL ELECTRODE OF THIN FILM TRANSISTOR ARRAY

CROSS-REFERENCE TO RELATED APPLICATION

This application claims the priority benefit of Taiwan application serial no. 94129055, filed on Aug. 25, 2005. All disclosure of the Taiwan application is incorporated herein by reference.

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention generally relates to a display panel, an active device array, and methods of fabricating the same. More particularly, the present invention relates to a multi-domain vertical alignment liquid crystal display (LCD) panel, a thin film transistor (TFT) array, and methods of fabricating the same.

2. Description of Related Art

It is the trend that LCD panels are to be with high brightness, high contrast, large display size, and wide view angle. In order to improve the view angle of the LCD panel, several wide-view-angle techniques have been proposed. The popular LCDs with wide view angle include, for example, the multi-domain vertical alignment (MVA) LCD, the in-plane switching (IPS) LCD, and the fringe field switching (FFS) LCD. For an MVA-LCD, plural slits are formed on the pixel electrode, for example. Plural protrusions are disposed on the color filter array substrate corresponding thereto. By matching the slits and the protrusions, liquid crystal molecules in the liquid crystal layer can tile in various directions and the wide-view-angle performance can be achieved.

FIG. 1 is a top view schematically illustrating a pixel of a conventional MVA-LCD. Referring to FIG. 1, a scan line 102, a data line 104, a thin film transistor (TFT) 120 and a pixel electrode 112 are disposed on a substrate (not shown). The thin film transistor (TFT) 120 includes a gate 106, a channel 108 and the source/drain 110a/110b, wherein the gate 106 is electrically connected to the scan line 102, the source 110a is electrically connected to the data line 104, and the drain 110b is electrically connected to the pixel electrode 112 via a contact opening 116.

Generally, in order to increase the viewing angle of the LCD, a plurality of strip slits 114 are formed in the pixel electrode 112, and a plurality of stripe protrusions 118 are formed on the opposite substrate (not shown) having a color filter layer. Therefore, the liquid crystal molecules disposed between the two substrates may have a variety of tilt directions by the aid of the slit 114 and the protrusion 118. Accordingly, the range of the view angle of the LCD may be enhanced.

Although the range of the view angle at the horizontal and vertical direction of the MVA-LCD described above is enhanced with the aid of the protrusions 118 and the slits 114, however, a color shift of an image in medium gray level may occur from a normal vision to a slant vision and thus result in a drop of display quality. FIG. 2 is a diagram illustrating the relationship between the applied voltage and the transmittance of a conventional MVA-LCD, wherein R-line refers to the V-T curve in a normal vision, and Q-line refers to the V-T curve in a slant vision. Referring to FIG. 2, under a low

driving voltage, the transmittance in the slant vision is greater than that in the normal vision. Therefore, the light leakage and the color shift of the MVA-LCD occur in the slant vision.

SUMMARY OF THE INVENTION

Accordingly, the present invention is directed to a TFT array, wherein changing the thickness of layers to increase the tilt directions of liquid crystal molecules and thus resolve the color shift or the light leakage forms structures with different heights.

The present invention is further directed to a MVA-LCD panel, wherein the TFT array mentioned above is used for providing more different cell gaps to increase the tilt directions of liquid crystal molecules and thus resolve the color shift or the light leakage.

In addition, the present invention is directed to a method for fabricating the TFT array mentioned above, wherein the tilt directions of liquid crystal molecules in the MVA-LCD panel can be increased, and the problem of color shift or light leakage can therefore be solved.

Furthermore, the present invention is directed to a method for fabricating the MVA-LCD panel mentioned above, wherein the tilt directions of liquid crystal molecules can be increased, and the problem of color shift or light leakage can therefore be solved.

The present invention provides a TFT array comprising: a substrate; a plurality of data lines and scan lines, disposed on the substrate for defining a plurality of pixel regions; a plurality of pixel structures, which are disposed in the pixel regions, electrically connected to the data lines and the scan lines, and driven by the data lines and the scan lines. Each pixel structure comprises a thin film transistor, electrically connected to the data lines and the scan lines; a pixel electrode, disposed over and electrically connected to the thin film transistor, the pixel electrode having a plurality of main slits; and a dielectric lining layer, disposed over the substrate and located between a portion of the pixel electrode and the substrate.

According to an embodiment of the present invention, the main slits are corresponding to the edge of the dielectric lining layers.

According to an embodiment of the present invention, each dielectric lining layer comprises a first lining sub-layer and a second lining sub-layer, and the height of the first lining sub-layer is different from that of the second lining sub-layer.

According to an embodiment of the present invention, each pixel electrode further has a plurality of fine slits, which are disposed at both sides of the main slits.

According to an embodiment of the present invention, each thin film transistor comprises: a gate, disposed over the substrate; a gate insulating layer, disposed over the substrate and covering the gate; a channel, disposed over the gate insulating layer and corresponding to the gate; a source/drain, disposed over the channel and electrically connected to the corresponding pixel electrode; and a passivation layer, disposed over the substrate and covering the channel and the source/drain.

According to an embodiment of the present invention, the gate insulating layer and the passivation layer may further extend out of the thin film transistor for constituting the dielectric lining layer.

The present invention provides a MVA-LCD panel, comprising: the TFT array mentioned above; an opposed substrate, disposed in corresponding to the thin film transistor array; and a liquid crystal layer, disposed between the thin film transistor array and the opposed substrate.

According to an embodiment of the present invention, the opposed substrate may be a color filter.

According to an embodiment of the present invention, the opposed substrate comprises a plurality of alignment protrusions. In addition, the alignment protrusions may take strip-shapes and are parallel to the main slits.

The present invention provides a method of fabricating a TFT array. First, a substrate is provided, wherein a plurality of pixel regions are defined on the substrate. Next, a gate metal layer is formed and then patterned for forming a gate in each pixel region. Then, a gate insulating layer is formed, wherein the gate insulating layer covers the gates. Thereafter, a plurality of channels is formed over the gate insulating layer, wherein the channels are corresponding to the gates. Next, a source/drain metal layer is formed and then patterned for forming a source/drain over each channel. Then, a passivation layer is formed over the substrate for covering the source/drains and the channels. Thereafter, the passivation layer and the gate insulating layer are patterned for forming a dielectric lining layer in each pixel region on the substrate. Next, an electrode layer is formed over the substrate and then patterned for forming a pixel electrode having a plurality of main slits in each pixel region, wherein the pixel electrode is electrically connected to the corresponding source/drain through the passivation layer, and a portion of the pixel electrode covers the corresponding dielectric lining layer.

The present invention also provides a method of fabricating a MVA-LCD panel. Besides the steps of forming the TFT array mentioned above, the fabricating method further comprises the steps of providing an opposed substrate and then forming a liquid crystal layer between the substrate and the opposed substrate.

According to the method of fabricating the TFT array and the MVA-LCD panel, the step of patterning the passivation layer and the gate insulating layer may comprise performing a mask process for defining contact openings in the passivation layer and forming the dielectric lining layer in each pixel region simultaneously, wherein the contact openings correspondingly expose a portion of each source/drain. In addition, the step of patterning the passivation layer and the gate insulating layer may further comprise performing another mask process for removing part of the dielectric lining layer to form a plurality of first lining sub-layers and second lining sub-layers, wherein the height of the first lining sub-layers is different from that of the second lining sub-layers.

In the present invention, the dielectric lining layer is formed with the gate insulating layer and the passivation layer on the TFT array, thus the thickness of the dielectric lining layer can be changed without any additional mask, and more different cell gaps are provided in the LCD panel. Consequently, the tilt directions of liquid crystal molecules are increased, and thus the color shift or the light leakage can be eliminated.

BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings are included to provide a further understanding of the invention, and are incorporated in and constitute a part of this specification. The drawings illustrate embodiments of the invention and, together with the description, serve to explain the principles of the invention.

FIG. 1 is a top view schematically illustrating a pixel of a conventional MVA-LCD.

FIG. 2 is a diagram illustrating the relationship between the applied voltage and the transmittance of a conventional MVA-LCD

FIG. 3 is a diagram illustrating the relationship between the applied voltage and the transmittance of a MVA-LCD according to the present invention.

FIG. 4A is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a first embodiment of the present invention.

FIG. 4B is a cross-sectional view schematically illustrating the MVA-LCD panel along line A-A' and line B-B'.

FIG. 5 schematically illustrates another type of the TFT array **210**.

FIG. 6A is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a second embodiment of the present invention.

FIG. 6B is a cross-sectional view schematically illustrating the MVA-LCD panel along line C-C'.

FIG. 7A is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a third embodiment of the present invention.

FIG. 7B is a cross-sectional view schematically illustrating the MVA-LCD panel along line D-D'.

FIG. 8A is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a third embodiment of the present invention.

FIG. 8B is a cross-sectional view schematically illustrating the MVA-LCD panel along line D-D'.

FIG. 9A to 9G schematically illustrate the fabricating process of the TFT arrays **210** according to the first, the second and the third embodiments of the present invention.

FIG. 10 illustrates forming the first lining sub-layer and the second lining sub-layer with different heights on the substrate.

FIG. 11 schematically illustrates a MVA-LCD panel of the present invention.

DESCRIPTION OF THE EMBODIMENTS

Reference will now be made in detail to the present preferred embodiments of the invention, examples of which are illustrated in the accompanying drawings. Wherever possible, the same reference numbers are used in the drawings and the description to refer to the same or like parts.

FIG. 3 is a diagram illustrating the relationship between the applied voltage and the transmittance of a MVA-LCD according to the present invention. Referring to FIG. 3, curve A and curve B represent V-T curves corresponding to different cell gaps, and curve C refers to a hybrid V-T curve derived from curve A and curve B. The present invention forms different cell gaps in one panel for attaining compensation by the different cell gaps. Therefore, the difference between V-T curves in the slant vision and the normal vision can be reduced, and the light leakage or the color shift can be eliminated.

FIG. 4A is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a first embodiment of the present invention. FIG. 4B is a cross-sectional view schematically illustrating the MVA-LCD panel along line A-A' and line B-B'.

Referring to FIG. 4A, the MVA-LCD panel **200** comprises a TFT array **210**, a color filter **220**, and a liquid crystal layer **230**. The TFT array **210** and the color filter **220** are substantially parallel. In addition, the liquid crystal layer **230** comprises a plurality of liquid crystal molecules **232** and is disposed between the TFT array **210** and the color filter **220**.

The TFT array **210** comprises a substrate **211**, a plurality of scan lines **212**, a plurality of data lines **213**, and a plurality of pixel structures. The scan lines **212** and data lines **213** are disposed on the substrate **211** for defining a plurality of pixel

regions **216**. The pixel structure are disposed in the pixel regions **216** respectively and electrically connected to the scan lines **212** and the data lines **213**.

Each pixel structure comprises a TFT **214**, a pixel electrode **215**, and a dielectric lining layer **217**. Wherein, the TFT **214** is disposed in the corresponding pixel regions **216** and electrically connected to the corresponding scan line **212** and data line **213** for being driven by the same. Each TFT **214** comprises a gate **2141**, a gate insulating layer **2142**, a channel **2143**, a source **2144**, a drain **2145**, and a passivation layer **2146**. The gate **2141** is disposed over the substrate **211**. The gate insulating layer **2142** is disposed over the substrate **211** and covers the gate **2141**. In addition, the channel **2143** is disposed over the gate insulating layer **2142** and corresponding to the gate **2141**. The source/drain **2144/2145** is disposed over the channel **2143**, and the source **2144** is electrically connected to the corresponding data line **213**. The passivation layer **2146** is disposed over the source/drain **2144/2145** for preserving the gate **2141**, the gate insulating **2142**, the channel **2143**, and the source/drain **2144/2145** from humidity or damage. Moreover, the passivation layer **2146** has a contact opening **2146a**, and the pixel electrode **215** is electrically connected to the drain **2145** of the corresponding TFT **214** in the pixel region **216** via the contact opening **2146a**.

In the present invention, the dielectric lining layer **217** may be constituted by the gate insulating layer **2142** and the passivation layer, which extends from the TFT **214**. The method for fabricating the dielectric lining layer **217** is, for example, removing the gate insulating layer **2142** and the passivation layer extending from the TFT **214** as forming the contact opening **2146a** in the passivation layer **2146**. In addition, the pixel electrode **215** may have a plurality of main slits **2151**, which are parallel and corresponding to the edge of the dielectric lining layer **217**.

The color filter **220** is parallel to the TFT array **210**. The liquid crystal layer **230** is composed of a plurality of liquid crystal molecule **232** and disposed between the TFT array **210** and the color filter **220**. Wherein, a plurality of alignment protrusions **222** are disposed on the surface of the color filter **220** and cooperate with the main slits **2151** of the pixel electrodes **215** to make the liquid crystal molecules tilting into different directions. In the embodiment, the alignment protrusions **222** may take strip-shapes and are parallel to the main slits **2151**.

Referring to FIGS. **4A** and **4B**, a part of the pixel electrode **215** is formed on the substrate **211**, and the other part of the pixel electrode **215** is formed on the dielectric lining layer **217**, wherein a difference in height is produced between the region I and the region II on the TFT array **210**. By the assistance of the two regions with different heights, more different domains are provided in the present invention, and thus the difference of the V-T curves in a normal vision and a slant vision can be reduced. Specifically, the region I and the region II have different cell gaps for producing different electric fields to make the liquid crystal molecules tilting into different directions. A self-compensation can therefore be achieved to eliminate the color shift or the light leakage.

Referring to FIG. **5**, which schematically illustrates another type of the TFT array **210**, wherein a plurality of fine slits **2151** is formed at both sides of each main slit **2151** on the pixel electrodes **215**. The fine slits **2151** can improve the response speed of the MVA-LCD panel **200**.

FIG. **6A** is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a second embodiment of the present invention. FIG. **6B** is a cross-sectional view schematically illustrating the MVA-LCD panel along line C-C'.

The structure illustrated in the second embodiment is similar to that in the first embodiment. Comparing to those in the first embodiment, positions of the removed part and the remained part of the dielectric lining layer **217** are changed. Similarly, the second embodiment forms more domains by the region I and the region II, which have different cell gaps, to reduce the difference of the V-T curves in a normal vision and a slant vision.

FIG. **7A** is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a third embodiment of the present invention. FIG. **7B** is a cross-sectional view schematically illustrating the MVA-LCD panel along line D-D'.

Similarly, the third embodiment removes part of the dielectric lining layer **217**, and then forms the pixel electrodes **215** on the substrate **211** and part of the dielectric lining layer **217**. It should be noted that only a part of the dielectric lining layer **217** for forming different cell gaps between two adjacent main slits **2151** of the pixel electrode **215**. By the different cell gaps, the liquid crystal molecules can tilt into different directions, and the self-compensation can therefore be achieved.

FIG. **8A** is a partial top view schematically illustrating a TFT array of a MVA-LCD panel according to a third embodiment of the present invention. FIG. **8B** is a cross-sectional view schematically illustrating the MVA-LCD panel along line D-D'. In the present invention, the dielectric lining layer **217** comprises a first lining sub-layer **2171** and a second lining sub-layer **2172**. There are three different cell gaps **h1**, **h2**, and **h3** being formed in the MVA-LCD panel **200** by the first lining sub-layer **2171** and the second lining sub-layer **2172** to provide more domains.

Accordingly, besides the embodiments mentioned above, the present invention can further form more than two lining sub-layers with different heights on the substrate, and thus the liquid crystal molecules have more tilt directions.

FIG. **9A** to **9G** schematically illustrate the fabricating process of the TFT arrays **210** according to the first, the second and the third embodiments of the present invention.

First, the substrate **211** is provided, wherein a plurality of pixel regions **216** arranged in matrix is defined on the substrate, as shown in FIG. **4A**. Referring to FIG. **9A**, a gate metal layer is formed on the substrate **211**, and a photolithography/etching process is performed to pattern the gate metal layer to form the gate **2141** in each pixel region **216**, as shown in FIG. **4A**. Next, referring to FIG. **9B**, the gate insulating layer **2142** is formed on the substrate **211** for covering the gate **2141**. The gate insulating layer **2142** may be formed by performing the plasma enhance chemical vapor deposition (PECVD) technique on the substrate.

Then, referring to FIG. **9C**, the channel **2143** is formed on the gate insulating layer **2142** corresponding to the gate **2141**. Next, referring to FIG. **9D**, a source/drain metal layer is formed on the substrate **211**, and a photolithography/etching process is performed to pattern the source/drain metal layer to form the source/drain **2144/2145** on each channel **2143**.

After that, referring to FIG. **9E**, the passivation layer **2146** is formed on the substrate **211** for covering the channel **2143**, and the source/drain **2144/2145**. Then, referring to FIG. **9F**, a mask process is performed to pattern the passivation layer **2146** and the gate insulating layer **2142**, wherein the contact opening **2146a** is defined in the passivation layer **2146** and the dielectric lining layer **217** is formed in the pixel regions **216**. The dielectric lining layer **217** comprises the gate insulating layer **2142** and the passivation layer **2146** extending outside the TFTs **214**.

Next, referring to FIG. **9G**, a electrode layer is formed on the substrate **211** and is patterned to form the pixel electrode

215 having parallel main slits 2151 in each pixel region 216. The pixel electrode 215 is electrically connected to the drain 2145 of the TFT 214 via the contact opening 2146a of the passivation layer 2146. A part of the pixel electrode 215 is disposed on the dielectric lining layer 217, and the other part is disposed on the substrate 211, therefore two region with different cell gaps are formed on the TFT array 210. Then, with different positions of the dielectric lining layer 217, the TFT arrays 210 according to the first, the second, and the third embodiments of the present invention can be formed.

In addition, after the step illustrated in FIG. 9F, an additional mask process can be performed to remove a part of the dielectric lining layer 217. Thus, referring to FIG. 10, the first lining sub-layer 2171 and the second lining sub-layer 2172 with different heights are formed on the substrate 211. Next, the pixel electrode 215 is formed on the substrate to form the TFT array 210 mentioned in the fourth embodiment.

Referring to FIG. 11, which schematically illustrates a MVA-LCD panel of the present invention. When fabricating a MVA-LCD panel 200, the opposed substrate 240, such as color filter, is provide. And then the liquid crystal layer 230 is formed between the TFT array 210 mentioned above and the opposed substrate 240 to form the MVA-LCD panel 200 mentioned in the above embodiments. Similarly, the opposed substrate 240 may have plural alignment protrusions 222, which cooperate with the main slits 2151 of the pixel electrodes 215 for attaining the effect of multi-domain vertical alignment.

In summary, the dielectric lining layer can be formed as patterning the gate insulating layer and the passivation layer on the TFT array. Therefore, the cell gap of the LCD panel can be modified without any additional mask process. The liquid crystal molecules have more different tilt directions, and the color shift or the light leakage can be drastically eliminated.

It will be apparent to those skilled in the art that various modifications and variations can be made to the structure of the present invention without departing from the scope or spirit of the invention. In view of the foregoing, it is intended that the present invention cover modifications and variations of this invention provided they fall within the scope of the following claims and their equivalents.

What is claimed is:

1. A thin film transistor array, comprising:

- a substrate;
- a plurality of data lines and scan lines, disposed on the substrate for defining a plurality of pixel regions;
- a plurality of pixel structures, which are disposed in the pixel regions, electrically connected to the data lines and the scan lines, and driven by the data lines and the scan lines, wherein each pixel structure comprises:
 - a thin film transistor, electrically connected to the data lines and the scan lines;
 - a pixel electrode, disposed over and electrically connected to the thin film transistor, the pixel electrode having a plurality of main slits; and
 - a dielectric lining layer, disposed over the substrate and located between a portion of the pixel electrode and the substrate,
- wherein the main slits are corresponding to the edge of the dielectric lining layers.

2. The thin film transistor array according to claim 1, wherein each dielectric lining layer comprises a first lining sub-layer and a second lining sub-layer, and the height of the first lining sub-layer is different from that of the second lining sub-layer.

3. The thin film transistor array according to claim 1, wherein each pixel electrode further has a plurality of fine slits, which are disposed at both sides of the main slits.

4. The thin film transistor array according to claim 1, wherein each thin film transistor comprises:

- a gate, disposed over the substrate;
- a gate insulating layer, disposed over the substrate and covering the gate;
- a channel, disposed over the gate insulating layer and corresponding to the gate;
- a source/drain, disposed over the channel and electrically connected to the corresponding pixel electrode; and
- a passivation layer, disposed over the substrate and covering the channel and the source/drain.

5. The thin film transistor array according to claim 4, wherein the gate insulating layer and the passivation layer further extend out of the thin film transistor for constituting the dielectric lining layer.

6. A multi-domain vertical alignment liquid crystal display panel, comprising:

a thin film transistor array, comprising:

- a substrate;
- a plurality of data lines and scan lines, disposed on the substrate for defining a plurality of pixel regions;
- a plurality of pixel structures, which are disposed in the pixel regions, electrically connected to the data lines and the scan lines, and driven by the data lines and the scan lines, wherein each pixel structure comprises:
 - a thin film transistor, electrically connected to the data lines and the scan lines;
 - a pixel electrode, disposed over and electrically connected to the thin film transistor, the pixel electrode having a plurality of main slits;
 - a dielectric lining layer, disposed over the substrate and located between a portion of the pixel electrode and the substrate;
- an opposed substrate, disposed in corresponding to the thin film transistor array; and
- a liquid crystal layer, disposed between the thin film transistor array and the opposed substrates, wherein the main slits are corresponding to the edge of the dielectric lining layers.

7. The multi-domain vertical alignment liquid crystal display panel according to claim 6, wherein each dielectric lining layer comprises a first lining sub-layer and a second lining sub-layer, and the height of the first lining sub-layer is different from that of the second lining sub-layer.

8. The multi-domain vertical alignment liquid crystal display panel according to claim 6, wherein each pixel electrode further has a plurality of fine slits, which are disposed at both sides of the main slits.

9. The multi-domain vertical alignment liquid crystal display panel according to claim 6, wherein each thin film transistor comprises:

- a gate, disposed over the substrate;
- a gate insulating layer, disposed over the substrate and covering the gate;
- a channel, disposed over the gate insulating layer and corresponding to the gate;
- a source/drain, disposed over the channel and electrically connected to the corresponding pixel electrode; and
- a passivation layer, disposed over the substrate and covering the channel and the source/drain.

10. The multi-domain vertical alignment liquid crystal display panel according to claim 9, wherein the gate insulating layer and the passivation layer further extend out of the thin film transistor for constituting the dielectric lining layer.

9

11. The multi-domain vertical alignment liquid crystal display panel according to claim **6**, wherein the opposed substrate is a color filter.

12. The multi-domain vertical alignment liquid crystal display panel according to claim **6**, wherein the opposed substrate comprises a plurality of alignment protrusions. 5

10

13. The multi-domain vertical alignment liquid crystal display panel according to claim **12**, wherein the alignment protrusions take strip-shapes and are parallel to the main slits.

* * * * *

专利名称(译)	多畴垂直对准LCD面板，具有多个主狭缝，对应于薄膜晶体管阵列的像素电极中的介电衬层的边缘		
公开(公告)号	US7508476	公开(公告)日	2009-03-24
申请号	US11/259425	申请日	2005-10-25
[标]申请(专利权)人(译)	黄椿		
申请(专利权)人(译)	黄骏逸		
当前申请(专利权)人(译)	中华映管股份有限公司.		
[标]发明人	HUANG CHUN YI		
发明人	HUANG, CHUN-YI		
IPC分类号	G02F1/1337		
CPC分类号	G02F1/133371 G02F1/1393 G02F1/133707 G02F2201/123		
审查员(译)	内尔姆斯, DAVID		
助理审查员(译)	海曼, JOHN		
优先权	094129055 2005-08-25 TW		
其他公开文献	US20070046878A1		
外部链接	Espacenet USPTO		

摘要(译)

提供了一种多畴垂直配向液晶显示面板，薄膜晶体管阵列及其制造方法。TFT阵列基板包括基板，数据线，扫描线和像素结构。数据线和扫描线布置在基板上以限定多个像素区域。每个像素结构布置在对应的像素区域中。每个像素结构包括TFT，像素电极和介电衬层。TFT电连接到相应的数据线和相应的扫描线。具有狭缝的像素电极放置在TFT上并与其电连接。介电衬层设置在基板上。部分介电衬层夹在像素电极和基板之间，以使液晶显示器内的液晶分子具有更多的倾斜方向。

